An Approach to Increase Integration Rate of Elements of a Cascaded-inverter Circuit

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Abstract In this paper we introduce an approach to increase integration rate of elements of a cascaded-inverter. Framework the approach we consider a heterostructure with special configuration. Several specific areas of the heterostructure should be doped by diffusion or ion implantation. Annealing of dopant and/or radiation defects should be optimized.

Keywords Cascaded-inverter, Optimization of Manufacturing, Increasing of Element Integration Rate

1. Introduction

An actual and intensively solving problems of solid state electronics is increasing of integration rate of elements of integrated circuits (p - n -junctions, their systems et al) [1-8]. Increasing of the integration rate leads to necessity to decrease their dimensions. To decrease the dimensions are using several approaches. They are widely using laser and microwave types of annealing of infused dopants. These types of annealing are also widely using for annealing of radiation defects, generated during ion implantation [9-17]. Using the approaches gives a possibility to increase integration rate of elements of integrated circuits through inhomogeneity of technological parameters due to generating inhomogeneous distribution of temperature. In this situation one can obtain decreasing dimensions of elements of integrated circuits [18] with account Arrhenius law [1,3]. Another approach to manufacture elements of integrated circuits with smaller dimensions is doping of heterostructure by diffusion or ion implantation [1-3]. However in this case optimization of dopant and/or radiation defects is required [18].

In this paper we consider a heterostructure. The heterostructure consist of a substrate and several epitaxial layers. Some sections have been manufactured in the epitaxial layers. Further we consider doping of these sections by diffusion or ion implantation. The doping gives a possibility to manufacture field-effect transistors framework a cascaded-inverter circuit so as it is shown on Figs. 1. The manufacturing leads to increasing density of elements of a cascaded-inverter circuit [4] due to presents of different materials in the heterostructure with different properties. It should be noted, that in the previous works manufacturing of integrated circuits and their elements in homogenous materials or some time in planar heterostructures. Using more simple structure in comparison with our case leads to smaller increasing of integration rate in comparison with processes in our heterostructure or do not leads to any increasing of the considered rate. After the above doping we consider optimized annealing of dopant and/or radiation defects. Optimization of annealing leads to manufacturing of more compact elements of integrated circuits and at the same time to increase of homogeneity of dopant distribution in doped area (in this situation one can find decreasing of local overheats during functioning of devices). Framework this paper we analyzed dynamics of redistribution of dopant and/or radiation defects during their annealing. The additional aim of this paper is development of analytical approach for modeling of technological process with account of nonlinearity of this process and variation of its parameters (diffusion coefficient of dopant and radiation, limit of solubility of dopant...). Using analytical approaches to model processes leads to decrease calculation time in comparison with numerical one. At the same time analytical approaches are more visible in comparison with numerical one.

Figure 1. The considered cascaded-inverter [4]

2. Method of Solution

In this section we determine spatio-temporal distributions of concentrations of infused and implanted dopants. To determine these distributions we calculate appropriate solutions of the second Fick's law [1, 3, 18]

$$\begin{aligned} \frac{\partial C(x, y, z, t)}{\partial t} = \\ = \frac{\partial}{\partial x} \left[D_c \frac{\partial C(x, y, z, t)}{\partial x} \right] + \frac{\partial}{\partial y} \left[D_c \frac{\partial C(x, y, z, t)}{\partial y} \right] + \frac{\partial}{\partial z} \left[D_c \frac{\partial C(x, y, z, t)}{\partial z} \right]. \end{aligned} \quad (1)$$

Boundary and initial conditions for the equations are

$$\begin{aligned} \left. \frac{\partial C(x, y, z, t)}{\partial x} \right|_{x=0} = 0, \quad \left. \frac{\partial C(x, y, z, t)}{\partial x} \right|_{x=L_x} = 0, \quad \left. \frac{\partial C(x, y, z, t)}{\partial y} \right|_{y=0} = 0, \quad \left. \frac{\partial C(x, y, z, t)}{\partial y} \right|_{x=L_y} = 0, \\ \left. \frac{\partial C(x, y, z, t)}{\partial z} \right|_{z=0} = 0, \quad \left. \frac{\partial C(x, y, z, t)}{\partial z} \right|_{x=L_z} = 0, \quad C(x, y, z, 0) = f(x, y, z). \end{aligned} \quad (2)$$

The function $C(x, y, z, t)$ describes the spatio-temporal distribution of concentration of dopant; T is the temperature of annealing; D_c is the dopant diffusion coefficient. Value of dopant diffusion coefficient could be changed with changing materials of heterostructure, with changing temperature of materials (including annealing), with changing concentrations of dopant and radiation defects. We approximate dependences of dopant diffusion coefficient on parameters by the following relation with account results in Refs. [20-22]

$$D_c = D_L(x, y, z, T) \left[1 + \xi \frac{C^\gamma(x, y, z, T)}{P^\gamma(x, y, z, T)} \right] \left[1 + \varsigma_1 \frac{V(x, y, z, T)}{V^*} + \varsigma_2 \frac{V^2(x, y, z, T)}{(V^*)^2} \right]. \quad (3)$$

Here the function $D_I(x,y,z,T)$ describes the spatial (in heterostructure) and temperature (due to Arrhenius law) dependences of diffusion coefficient of dopant. The function $P(x,y,z,T)$ describes the limit of solubility of dopant. Parameter $\gamma \in [1,3]$ describes average quantity of charged defects interacted with atom of dopant [20]. The function $V(x,y,z,t)$ describes the spatio-temporal distribution of concentration of radiation vacancies. Parameter V^* describes the equilibrium distribution of concentration of vacancies. The considered concentrational dependence of dopant diffusion coefficient has been described in details in [20]. It should be noted, that using diffusion type of doping did not generation radiation defects. In this situation $\zeta_1 = \zeta_2 = 0$. We determine spatio-temporal distributions of concentrations of radiation defects by solving the following system of equations [21,22]

$$\begin{aligned} \frac{\partial I(x,y,z,t)}{\partial t} = & \frac{\partial}{\partial x} \left[D_I(x,y,z,T) \frac{\partial I(x,y,z,t)}{\partial x} \right] + \frac{\partial}{\partial y} \left[D_I(x,y,z,T) \frac{\partial I(x,y,z,t)}{\partial y} \right] + \\ & + \frac{\partial}{\partial z} \left[D_I(x,y,z,T) \frac{\partial I(x,y,z,t)}{\partial z} \right] - k_{I,V}(x,y,z,T) I(x,y,z,t) V(x,y,z,t) - \\ & - k_{I,I}(x,y,z,T) I^2(x,y,z,t) \end{aligned} \quad (4)$$

$$\begin{aligned} \frac{\partial V(x,y,z,t)}{\partial t} = & \frac{\partial}{\partial x} \left[D_V(x,y,z,T) \frac{\partial V(x,y,z,t)}{\partial x} \right] + \frac{\partial}{\partial y} \left[D_V(x,y,z,T) \frac{\partial V(x,y,z,t)}{\partial y} \right] + \\ & + \frac{\partial}{\partial z} \left[D_V(x,y,z,T) \frac{\partial V(x,y,z,t)}{\partial z} \right] - k_{I,V}(x,y,z,T) I(x,y,z,t) V(x,y,z,t) + \\ & + k_{V,V}(x,y,z,T) V^2(x,y,z,t). \end{aligned}$$

Boundary and initial conditions for these equations are

$$\begin{aligned} \left. \frac{\partial \rho(x,y,z,t)}{\partial x} \right|_{x=0} = 0, \quad \left. \frac{\partial \rho(x,y,z,t)}{\partial x} \right|_{x=L_x} = 0, \quad \left. \frac{\partial \rho(x,y,z,t)}{\partial y} \right|_{y=0} = 0, \quad \left. \frac{\partial \rho(x,y,z,t)}{\partial y} \right|_{y=L_y} = 0, \\ \left. \frac{\partial \rho(x,y,z,t)}{\partial z} \right|_{z=0} = 0, \quad \left. \frac{\partial \rho(x,y,z,t)}{\partial z} \right|_{z=L_z} = 0, \quad \rho(x,y,z,0) = f_p(x,y,z). \end{aligned} \quad (5)$$

Here $\rho = I, V$. The function $I(x,y,z,t)$ describes the spatio-temporal distribution of concentration of radiation interstitials; $D_{\rho}(x,y,z,T)$ are the diffusion coefficients of point radiation defects; terms $V^2(x,y,z,t)$ and $I^2(x,y,z,t)$ correspond to generation divacancies and diinterstitials; $k_{I,V}(x,y,z,T)$ is the parameter of recombination of point radiation defects; $k_{I,I}(x,y,z,T)$ and $k_{V,V}(x,y,z,T)$ are the parameters of generation of simplest complexes of point radiation defects.

Further we determine distributions in space and time of concentrations of divacancies $\Phi_V(x,y,z,t)$ and diinterstitials $\Phi_I(x,y,z,t)$ by solving the following system of equations [21,22]

$$\begin{aligned} \frac{\partial \Phi_I(x,y,z,t)}{\partial t} = & \frac{\partial}{\partial x} \left[D_{\Phi_I}(x,y,z,T) \frac{\partial \Phi_I(x,y,z,t)}{\partial x} \right] + \frac{\partial}{\partial y} \left[D_{\Phi_I}(x,y,z,T) \frac{\partial \Phi_I(x,y,z,t)}{\partial y} \right] + \\ & + \frac{\partial}{\partial z} \left[D_{\Phi_I}(x,y,z,T) \frac{\partial \Phi_I(x,y,z,t)}{\partial z} \right] + k_{I,I}(x,y,z,T) I^2(x,y,z,t) - k_I(x,y,z,T) I(x,y,z,t) \end{aligned} \quad (6)$$

$$\frac{\partial \Phi_V(x,y,z,t)}{\partial t} = \frac{\partial}{\partial x} \left[D_{\Phi_V}(x,y,z,T) \frac{\partial \Phi_V(x,y,z,t)}{\partial x} \right] + \frac{\partial}{\partial y} \left[D_{\Phi_V}(x,y,z,T) \frac{\partial \Phi_V(x,y,z,t)}{\partial y} \right] +$$

$$+ \frac{\partial}{\partial z} \left[D_{\Phi_V}(x, y, z, T) \frac{\partial \Phi_V(x, y, z, t)}{\partial z} \right] + k_{V,V}(x, y, z, T) V^2(x, y, z, t) - k_V(x, y, z, T) V(x, y, z, t).$$

Boundary and initial conditions for these equations are

$$\begin{aligned} \left. \frac{\partial \Phi_\rho(x, y, z, t)}{\partial x} \right|_{x=0} = 0, \quad \left. \frac{\partial \Phi_\rho(x, y, z, t)}{\partial x} \right|_{x=L_x} = 0, \quad \left. \frac{\partial \Phi_\rho(x, y, z, t)}{\partial y} \right|_{y=0} = 0, \quad \left. \frac{\partial \Phi_\rho(x, y, z, t)}{\partial y} \right|_{y=L_y} = 0, \\ \left. \frac{\partial \Phi_\rho(x, y, z, t)}{\partial z} \right|_{z=0} = 0, \quad \left. \frac{\partial \Phi_\rho(x, y, z, t)}{\partial z} \right|_{z=L_z} = 0, \\ \Phi_I(x, y, z, 0) = f_{\Phi_I}(x, y, z), \quad \Phi_V(x, y, z, 0) = f_{\Phi_V}(x, y, z). \end{aligned} \quad (7)$$

Here $D_{\Phi_\rho}(x, y, z, T)$ are the diffusion coefficients of the above complexes of radiation defects; $k_I(x, y, z, T)$ and $k_V(x, y, z, T)$ are the parameters of decay of these complexes.

We calculate distributions of concentrations of point radiation defects in space and time by recently elaborated approach [18]. The approach based on transformation of approximations of diffusion coefficients in the following form:

$D_\rho(x, y, z, T) = D_{0\rho} [1 + \varepsilon_\rho g_\rho(x, y, z, T)]$, where $D_{0\rho}$ are the average values of diffusion coefficients, $0 \leq \varepsilon_\rho < 1$, $|g_\rho(x, y, z, T)| \leq 1$, $\rho = I, V$. We also used analogous transformation of approximations of parameters of recombination of point defects and parameters of generation of their complexes: $k_{I,V}(x, y, z, T) = k_{0I,V} [1 + \varepsilon_{I,V} g_{I,V}(x, y, z, T)]$, $k_{I,I}(x, y, z, T) = k_{0I,I} [1 + \varepsilon_{I,I} g_{I,I}(x, y, z, T)]$ and $k_{V,V}(x, y, z, T) = k_{0V,V} [1 + \varepsilon_{V,V} g_{V,V}(x, y, z, T)]$, where $k_{0\rho 1}, k_{0\rho 2}$ are the their average values, $0 \leq \varepsilon_{I,V} < 1$, $0 \leq \varepsilon_{I,I} < 1$, $0 \leq \varepsilon_{V,V} < 1$, $|g_{I,V}(x, y, z, T)| \leq 1$, $|g_{I,I}(x, y, z, T)| \leq 1$, $|g_{V,V}(x, y, z, T)| \leq 1$. Let us introduce the following dimensionless variables:

$\tilde{I}(x, y, z, t) = I(x, y, z, t)/I^*$, $\tilde{V}(x, y, z, t) = V(x, y, z, t)/V^*$, $\omega = L^2 k_{0I,V} / \sqrt{D_{0I} D_{0V}}$, $\Omega_\rho = L^2 k_{0\rho, \rho} / \sqrt{D_{0I} D_{0V}}$, $\mathcal{G} = \sqrt{D_{0I} D_{0V}} t / L^2$, $\chi = x/L_x$, $\eta = y/L_y$, $\phi = z/L_z$. The introduction leads to transformation of Eqs.(4) and conditions (5) to the following form

$$\begin{aligned} \frac{\partial \tilde{I}(\chi, \eta, \phi, \mathcal{G})}{\partial \mathcal{G}} &= \frac{D_{0I}}{\sqrt{D_{0I} D_{0V}}} \frac{\partial}{\partial \chi} \left\{ [1 + \varepsilon_I g_I(\chi, \eta, \phi, T)] \frac{\partial \tilde{I}(\chi, \eta, \phi, \mathcal{G})}{\partial \chi} \right\} + \frac{\partial}{\partial \eta} \{ [1 + \varepsilon_I g_I(\chi, \eta, \phi, T)] \times \\ &\times \frac{\partial \tilde{I}(\chi, \eta, \phi, \mathcal{G})}{\partial \eta} \} \left\{ \frac{D_{0I}}{\sqrt{D_{0I} D_{0V}}} + \frac{D_{0I}}{\sqrt{D_{0I} D_{0V}}} \frac{\partial}{\partial \phi} \left\{ [1 + \varepsilon_I g_I(\chi, \eta, \phi, T)] \frac{\partial \tilde{I}(\chi, \eta, \phi, \mathcal{G})}{\partial \phi} \right\} - \tilde{I}(\chi, \eta, \phi, \mathcal{G}) \times \right. \\ &\times \omega [1 + \varepsilon_{I,V} g_{I,V}(\chi, \eta, \phi, T)] \tilde{V}(\chi, \eta, \phi, \mathcal{G}) - \Omega_I [1 + \varepsilon_{I,I} g_{I,I}(\chi, \eta, \phi, T)] \tilde{I}^2(\chi, \eta, \phi, \mathcal{G}) \quad (8) \\ \frac{\partial \tilde{V}(\chi, \eta, \phi, \mathcal{G})}{\partial \mathcal{G}} &= \frac{D_{0V}}{\sqrt{D_{0I} D_{0V}}} \frac{\partial}{\partial \chi} \left\{ [1 + \varepsilon_V g_V(\chi, \eta, \phi, T)] \frac{\partial \tilde{V}(\chi, \eta, \phi, \mathcal{G})}{\partial \chi} \right\} + \frac{\partial}{\partial \eta} \{ [1 + \varepsilon_V g_V(\chi, \eta, \phi, T)] \times \\ &\times \frac{\partial \tilde{V}(\chi, \eta, \phi, \mathcal{G})}{\partial \eta} \} \left\{ \frac{D_{0V}}{\sqrt{D_{0I} D_{0V}}} + \frac{D_{0V}}{\sqrt{D_{0I} D_{0V}}} \frac{\partial}{\partial \phi} \left\{ [1 + \varepsilon_V g_V(\chi, \eta, \phi, T)] \frac{\partial \tilde{V}(\chi, \eta, \phi, \mathcal{G})}{\partial \phi} \right\} - \tilde{I}(\chi, \eta, \phi, \mathcal{G}) \times \right. \\ &\times \omega [1 + \varepsilon_{I,V} g_{I,V}(\chi, \eta, \phi, T)] \tilde{V}(\chi, \eta, \phi, \mathcal{G}) - \Omega_V [1 + \varepsilon_{V,V} g_{V,V}(\chi, \eta, \phi, T)] \tilde{V}^2(\chi, \eta, \phi, \mathcal{G}) \\ \left. \frac{\partial \tilde{\rho}(\chi, \eta, \phi, \mathcal{G})}{\partial \chi} \right|_{\chi=0} &= 0, \quad \left. \frac{\partial \tilde{\rho}(\chi, \eta, \phi, \mathcal{G})}{\partial \chi} \right|_{\chi=1} = 0, \quad \left. \frac{\partial \tilde{\rho}(\chi, \eta, \phi, \mathcal{G})}{\partial \eta} \right|_{\eta=0} = 0, \quad \left. \frac{\partial \tilde{\rho}(\chi, \eta, \phi, \mathcal{G})}{\partial \eta} \right|_{\eta=1} = 0, \end{aligned}$$

$$\left. \frac{\partial \tilde{\rho}(\chi, \eta, \phi, \vartheta)}{\partial \phi} \right|_{\phi=0} = 0, \quad \left. \frac{\partial \tilde{\rho}(\chi, \eta, \phi, \vartheta)}{\partial \phi} \right|_{\phi=1} = 0, \quad \tilde{\rho}(\chi, \eta, \phi, \vartheta) = \frac{f_{\rho}(\chi, \eta, \phi, \vartheta)}{\rho^*}. \quad (9)$$

We determine solutions of Eqs.(8) with conditions (9) framework recently introduced approach [18], i.e. as the power series

$$\tilde{\rho}(\chi, \eta, \phi, \vartheta) = \sum_{i=0}^{\infty} \varepsilon_{\rho}^i \sum_{j=0}^{\infty} \omega^j \sum_{k=0}^{\infty} \Omega_{\rho}^k \tilde{\rho}_{ijk}(\chi, \eta, \phi, \vartheta). \quad (10)$$

Substitution of the series (10) into Eqs.(8) and conditions (9) gives us possibility to obtain equations for initial-order approximations of concentration of point defects $\tilde{I}_{000}(\chi, \eta, \phi, \vartheta)$ and $\tilde{V}_{000}(\chi, \eta, \phi, \vartheta)$ and corrections for them $\tilde{I}_{ijk}(\chi, \eta, \phi, \vartheta)$ and $\tilde{V}_{ijk}(\chi, \eta, \phi, \vartheta)$, $i \geq 1, j \geq 1, k \geq 1$. The equations are presented in the Appendix. Solutions of the equations could be obtained by standard Fourier approach [24,25]. The solutions are presented in the Appendix.

Now we calculate distributions of concentrations of simplest complexes of point radiation defects in space and time. To determine the distributions we transform approximations of diffusion coefficients in the following form: $D_{\phi\rho}(x, y, z, T) = D_{0\phi\rho}[1 + \varepsilon_{\phi\rho}g_{\phi\rho}(x, y, z, T)]$, where $D_{0\phi\rho}$ are the average values of diffusion coefficients. In this situation the Eqs.(6) could be written as

$$\begin{aligned} \frac{\partial \Phi_I(x, y, z, t)}{\partial t} &= D_{0\Phi I} \frac{\partial}{\partial x} \left\{ [1 + \varepsilon_{\Phi I} g_{\Phi I}(x, y, z, T)] \frac{\partial \Phi_I(x, y, z, t)}{\partial x} \right\} + k_{I,I}(x, y, z, T) I^2(x, y, z, t) + \\ &+ D_{0\Phi I} \frac{\partial}{\partial y} \left\{ [1 + \varepsilon_{\Phi I} g_{\Phi I}(x, y, z, T)] \frac{\partial \Phi_I(x, y, z, t)}{\partial y} \right\} + D_{0\Phi I} \frac{\partial}{\partial z} \left\{ [1 + \varepsilon_{\Phi I} g_{\Phi I}(x, y, z, T)] \frac{\partial \Phi_I(x, y, z, t)}{\partial z} \right\} - \\ &- k_I(x, y, z, T) I(x, y, z, t) \\ \frac{\partial \Phi_V(x, y, z, t)}{\partial t} &= D_{0\Phi V} \frac{\partial}{\partial x} \left\{ [1 + \varepsilon_{\Phi V} g_{\Phi V}(x, y, z, T)] \frac{\partial \Phi_V(x, y, z, t)}{\partial x} \right\} + k_{I,I}(x, y, z, T) I^2(x, y, z, t) + \\ &+ D_{0\Phi V} \frac{\partial}{\partial y} \left\{ [1 + \varepsilon_{\Phi V} g_{\Phi V}(x, y, z, T)] \frac{\partial \Phi_V(x, y, z, t)}{\partial y} \right\} + D_{0\Phi V} \frac{\partial}{\partial z} \left\{ [1 + \varepsilon_{\Phi V} g_{\Phi V}(x, y, z, T)] \frac{\partial \Phi_V(x, y, z, t)}{\partial z} \right\} - \\ &- k_I(x, y, z, T) I(x, y, z, t). \end{aligned}$$

Farther we determine solutions of above equations as the following power series

$$\Phi_{\rho}(x, y, z, t) = \sum_{i=0}^{\infty} \varepsilon_{\Phi\rho}^i \Phi_{\rho i}(x, y, z, t). \quad (11)$$

Now we used the series (11) into Eqs.(6) and appropriate boundary and initial conditions. The using gives the possibility to obtain equations for initial-order approximations of concentrations of complexes of defects $\Phi_{p0}(x,y,z,t)$, corrections for them $\Phi_{pi}(x,y,z,t)$ (for them $i \geq 1$) and boundary and initial conditions for them. We remove equations and conditions to the Appendix. Solutions of the equations have been calculated by standard approaches [24,25] and presented in the Appendix.

Now we calculate distribution of concentration of dopant in space and time by using the approach, which was used for analysis of radiation defects. To use the approach we consider following transformation of approximation of dopant diffusion coefficient: $D_L(x,y,z,T) = D_{0L}[1 + \varepsilon_L g_L(x,y,z,T)]$, where D_{0L} is the average value of dopant diffusion coefficient, $0 \leq \varepsilon_L < 1$, $|g_L(x,y,z,T)| \leq 1$. Farther we consider solution of Eq. (1) as the following series:

$$C(x,y,z,t) = \sum_{i=0}^{\infty} \varepsilon_L^i \sum_{j=1}^{\infty} \xi^j C_{ij}(x,y,z,t).$$

Using the relation into Eq.(1) and conditions (2) leads to obtaining equations for the functions $C_{ij}(x,y,z,t)$ ($i \geq 1, j \geq 1$), boundary and initial conditions for them. The equations are presented in the Appendix. Solutions of the equations have been calculated by standard approaches (see, for example, [24,25]). The solutions are presented in the Appendix.

We analyzed distributions of concentrations of dopant and radiation defects in space and time analytically by using the second-order approximations on all parameters, which have been used in appropriate series. Usually the second-order approximations are enough good approximations to make qualitative analysis and to obtain quantitative results. All analytical results have been checked by numerical simulation.

3. Discussion

In this section we analyzed spatio-temporal distributions of concentrations of dopants. Figs. 2 shows typical spatial distributions of concentrations of dopants in neighborhood of interfaces of heterostructures. We calculate these distributions of concentrations of dopants under the following condition: value of dopant diffusion coefficient in doped area is larger, than value of dopant diffusion coefficient in nearest areas. One can find from Figs. 2 increasing of compactness of dopant distributions in doped area with increasing of homogeneity of distribution of concentration of dopant at one time. In this situation one can obtain increasing of density of field-effect transistors framework considered circuit and at one time decreasing local overheats during functioning of devices in doped

areas. It should be noted, that transistors and p - n -junctions usually manufacturing in homogenous materials with appropriate wide distributions of dopant (curves 1 on Figs. 2) [1-8]. In this situation one can find devices with larger dimensions and more spread boundaries. Changing relation between values of dopant diffusion coefficients leads to opposite result (see Figs. 3).

Figure 2a. Dependences of concentration of dopant, infused in heterostructure from Figs. 1, on coordinate in direction, which is perpendicular to interface between epitaxial layer substrate. Difference between values of dopant diffusion coefficient in layers of heterostructure increases with increasing of number of curves. Value of dopant diffusion coefficient in the epitaxial layer is larger, than value of dopant diffusion coefficient in the substrate

Figure 2b. Dependences of concentration of dopant, implanted in heterostructure from Figs. 1, on coordinate in direction, which is perpendicular to interface between epitaxial layer substrate. Difference between values of dopant diffusion coefficient in layers of heterostructure increases with increasing of number of curves. Value of dopant diffusion coefficient in the epitaxial layer is larger, than value of dopant diffusion coefficient in the substrate. Curve 1 corresponds to homogenous sample and annealing time $\Theta = 0.0048 (L_x^2 + L_y^2 + L_z^2)/D_0$. Curve 2 corresponds to homogenous sample and annealing time $\Theta = 0.0057 (L_x^2 + L_y^2 + L_z^2)/D_0$. Curves 3 and 4 correspond to heterostructure from Figs. 1; annealing times $\Theta = 0.0048 (L_x^2 + L_y^2 + L_z^2)/D_0$ and $\Theta = 0.0057 (L_x^2 + L_y^2 + L_z^2)/D_0$, respectively

Figure 3a. Distributions of concentration of dopant, infused in average section of epitaxial layer of heterostructure from Figs. 1 in direction parallel to interface between epitaxial layer and substrate of heterostructure. Difference between values of dopant diffusion coefficients increases with increasing of number of curves. Value of dopant diffusion coefficient in this section is smaller, than value of dopant diffusion coefficient in nearest sections

Figure 3b. Calculated distributions of implanted dopant in epitaxial layers of heterostructure. Solid lines are spatial distributions of implanted dopant in system of two epitaxial layers. Dashed lines are spatial distributions of implanted dopant in one epitaxial layer. Annealing time increases with increasing of number of curves

It should be noted, that framework the considered approach one shall optimize annealing of dopant and/or radiation defects. Reason for this optimization is following. If annealing of dopant is short, than dopant has no time to achieve interface between materials of heterostructure and modification of distribution of dopant due to the interface could not be obtained. In this situation one can find recently introduced technological schemes [1-8]. If annealing time is very large, than distribution of dopant will be too homogenous. In this situation interface between doped and undoped areas will be almost absent. In this situation it should be used compromise value of annealing time. This choosing was absents in related works and became original procedure of author of this paper. To make this choosing we use recently introduced criterion [26-34]. The choosing based on approximation of real distribution of concentration of dopant by step-wise function $\psi(x, y, z)$ (see Figs. 4). Farther the required values of optimal

annealing time have been calculated by minimization the following mean-squared error

$$U = \frac{1}{L_x L_y L_z} \int_0^{L_x} \int_0^{L_y} \int_0^{L_z} [C(x, y, z, \Theta) - \psi(x, y, z)]^2 dz dy dx. \quad (12)$$

Figure 4a. Distributions of concentration of infused dopant in depth of heterostructure from Fig. 1 for different values of annealing time (curves 2-4) and idealized step-wise approximation (curve 1). Increasing of number of curve corresponds to increasing of annealing time

Figure 4b. Distributions of concentration of implanted dopant in depth of heterostructure from Fig. 1 for different values of annealing time (curves 2-4) and idealized step-wise approximation (curve 1). Increasing of number of curve corresponds to increasing of annealing time

We show optimal values of annealing time as functions of several parameters on Figs. 5. It is known, that standard step of manufactured ion-doped structures is annealing of radiation defects. In the ideal case after finishing this annealing dopant achieves interface between layers of heterostructure. If the dopant has no enough time to achieve the interface, it is practicably to anneal the dopant additionally. The Fig. 5b shows the described dependences of optimal values of additional annealing time for the same parameters as for Fig. 5a. Necessity to anneal radiation defects leads to smaller values of optimal annealing of implanted dopant in comparison with optimal annealing time of infused dopant.

Figure 5a. Dimensionless optimal annealing time of infused dopant as a function of several parameters. Curve 1 describes the dependence of the annealing time on the relation a/L and $\xi=\gamma=0$ for equal to each other values of dopant diffusion coefficient in all parts of heterostructure. Curve 2 describes the dependence of the annealing time on value of parameter ε for $a/L=1/2$ and $\xi=\gamma=0$. Curve 3 describes the dependence of the annealing time on value of parameter ξ for $a/L=1/2$ and $\varepsilon=\gamma=0$. Curve 4 describes the dependence of the annealing time on value of parameter γ for $a/L=1/2$ and $\varepsilon=\xi=0$

Figure 5b. Dimensionless optimal annealing time of implanted dopant as a function of several parameters. Curve 1 describes the dependence of the annealing time on the relation a/L and $\xi=\gamma=0$ for equal to each other values of dopant diffusion coefficient in all parts of heterostructure. Curve 2 describes the dependence of the annealing time on value of parameter ε for $a/L=1/2$ and $\xi=\gamma=0$. Curve 3 describes the dependence of the annealing time on value of parameter ξ for $a/L=1/2$ and $\varepsilon=\gamma=0$. Curve 4 describes the dependence of the annealing time on value of parameter γ for $a/L=1/2$ and $\varepsilon=\xi=0$

4. Conclusions

In this paper we introduce an approach to increase integration rate of element of a cascaded-inverter circuit. The approach gives us possibility to decrease area of the elements with decreasing of the element's thickness. At the same time we introduce an analytical approach to model technological process with account nonlinearity of this process and variation of different technological processes.

Appendix

Equations for the functions $\tilde{I}_{ijk}(\chi, \eta, \phi, \vartheta)$ and $\tilde{V}_{ijk}(\chi, \eta, \phi, \vartheta)$, $i \geq 0, j \geq 0, k \geq 0$ and conditions for them

$$\begin{aligned} \frac{\partial \tilde{I}_{000}(\chi, \eta, \phi, \vartheta)}{\partial \vartheta} &= \sqrt{\frac{D_{0I}}{D_{0V}}} \left[\frac{\partial^2 \tilde{I}_{000}(\chi, \eta, \phi, \vartheta)}{\partial \chi^2} + \frac{\partial^2 \tilde{I}_{000}(\chi, \eta, \phi, \vartheta)}{\partial \eta^2} + \frac{\partial^2 \tilde{I}_{000}(\chi, \eta, \phi, \vartheta)}{\partial \phi^2} \right] \\ \frac{\partial \tilde{V}_{000}(\chi, \eta, \phi, \vartheta)}{\partial \vartheta} &= \sqrt{\frac{D_{0V}}{D_{0I}}} \left[\frac{\partial^2 \tilde{V}_{000}(\chi, \eta, \phi, \vartheta)}{\partial \chi^2} + \frac{\partial^2 \tilde{V}_{000}(\chi, \eta, \phi, \vartheta)}{\partial \eta^2} + \frac{\partial^2 \tilde{V}_{000}(\chi, \eta, \phi, \vartheta)}{\partial \phi^2} \right], \\ \frac{\partial \tilde{I}_{i00}(\chi, \vartheta)}{\partial \vartheta} &= \sqrt{\frac{D_{0I}}{D_{0V}}} \left[\frac{\partial^2 \tilde{I}_{i00}(\chi, \eta, \phi, \vartheta)}{\partial \chi^2} + \frac{\partial^2 \tilde{I}_{i00}(\chi, \eta, \phi, \vartheta)}{\partial \eta^2} + \frac{\partial^2 \tilde{I}_{i00}(\chi, \eta, \phi, \vartheta)}{\partial \phi^2} \right] + \sqrt{\frac{D_{0I}}{D_{0V}}} \times \\ &\times \left\{ \frac{\partial}{\partial \chi} \left[g_i(\chi, \eta, \phi, T) \frac{\partial \tilde{I}_{i-100}(\chi, \eta, \phi, \vartheta)}{\partial \chi} \right] + \frac{\partial}{\partial \eta} \left[g_i(\chi, \eta, \phi, T) \frac{\partial \tilde{I}_{i-100}(\chi, \eta, \phi, \vartheta)}{\partial \eta} \right] + \right. \\ &\left. + \frac{\partial}{\partial \phi} \left[g_i(\chi, \eta, \phi, T) \frac{\partial \tilde{I}_{i-100}(\chi, \eta, \phi, \vartheta)}{\partial \phi} \right] \right\}, \quad i \geq 1, \end{aligned}$$

$$\begin{aligned}
\frac{\partial \tilde{V}_{i00}(\chi, \vartheta)}{\partial \vartheta} &= \sqrt{\frac{D_{0V}}{D_{0I}}} \left[\frac{\partial^2 \tilde{V}_{i00}(\chi, \eta, \phi, \vartheta)}{\partial \chi^2} + \frac{\partial^2 \tilde{V}_{i00}(\chi, \eta, \phi, \vartheta)}{\partial \eta^2} + \frac{\partial^2 \tilde{V}_{i00}(\chi, \eta, \phi, \vartheta)}{\partial \phi^2} \right] + \sqrt{\frac{D_{0V}}{D_{0I}}} \times \\
&\times \frac{\partial}{\partial \chi} \left[g_v(\chi, \eta, \phi, T) \frac{\partial \tilde{V}_{i-100}(\chi, \eta, \phi, \vartheta)}{\partial \chi} \right] + \sqrt{\frac{D_{0V}}{D_{0I}}} \frac{\partial}{\partial \eta} \left[g_v(\chi, \eta, \phi, T) \frac{\partial \tilde{V}_{i-100}(\chi, \eta, \phi, \vartheta)}{\partial \eta} \right] + \\
&+ \sqrt{\frac{D_{0V}}{D_{0I}}} \frac{\partial}{\partial \phi} \left[g_v(\chi, \eta, \phi, T) \frac{\partial \tilde{V}_{i-100}(\chi, \eta, \phi, \vartheta)}{\partial \phi} \right], i \geq l, \\
\frac{\partial \tilde{I}_{010}(\chi, \eta, \phi, \vartheta)}{\partial \vartheta} &= \sqrt{\frac{D_{0I}}{D_{0V}}} \left[\frac{\partial^2 \tilde{I}_{010}(\chi, \eta, \phi, \vartheta)}{\partial \chi^2} + \frac{\partial^2 \tilde{I}_{010}(\chi, \eta, \phi, \vartheta)}{\partial \eta^2} + \frac{\partial^2 \tilde{I}_{010}(\chi, \eta, \phi, \vartheta)}{\partial \phi^2} \right] - \\
&- [1 + \varepsilon_{I,V} g_{I,V}(\chi, \eta, \phi, T)] \tilde{I}_{000}(\chi, \eta, \phi, \vartheta) \tilde{V}_{000}(\chi, \eta, \phi, \vartheta) \\
\frac{\partial \tilde{V}_{010}(\chi, \eta, \phi, \vartheta)}{\partial \vartheta} &= \sqrt{\frac{D_{0V}}{D_{0I}}} \left[\frac{\partial^2 \tilde{V}_{010}(\chi, \eta, \phi, \vartheta)}{\partial \chi^2} + \frac{\partial^2 \tilde{V}_{010}(\chi, \eta, \phi, \vartheta)}{\partial \eta^2} + \frac{\partial^2 \tilde{V}_{010}(\chi, \eta, \phi, \vartheta)}{\partial \phi^2} \right] - \\
&- [1 + \varepsilon_{I,V} g_{I,V}(\chi, \eta, \phi, T)] \tilde{I}_{000}(\chi, \eta, \phi, \vartheta) \tilde{V}_{000}(\chi, \eta, \phi, \vartheta); \\
\frac{\partial \tilde{I}_{020}(\chi, \eta, \phi, \vartheta)}{\partial \vartheta} &= \sqrt{\frac{D_{0I}}{D_{0V}}} \left[\frac{\partial^2 \tilde{I}_{020}(\chi, \eta, \phi, \vartheta)}{\partial \chi^2} + \frac{\partial^2 \tilde{I}_{020}(\chi, \eta, \phi, \vartheta)}{\partial \eta^2} + \frac{\partial^2 \tilde{I}_{020}(\chi, \eta, \phi, \vartheta)}{\partial \phi^2} \right] - \\
&- [1 + \varepsilon_{I,V} g_{I,V}(\chi, \eta, \phi, T)] [\tilde{I}_{010}(\chi, \eta, \phi, \vartheta) \tilde{V}_{000}(\chi, \eta, \phi, \vartheta) + \tilde{I}_{000}(\chi, \eta, \phi, \vartheta) \tilde{V}_{010}(\chi, \eta, \phi, \vartheta)] \\
\frac{\partial \tilde{V}_{020}(\chi, \eta, \phi, \vartheta)}{\partial \vartheta} &= \sqrt{\frac{D_{0I}}{D_{0V}}} \left[\frac{\partial^2 \tilde{V}_{020}(\chi, \eta, \phi, \vartheta)}{\partial \chi^2} + \frac{\partial^2 \tilde{V}_{020}(\chi, \eta, \phi, \vartheta)}{\partial \eta^2} + \frac{\partial^2 \tilde{V}_{020}(\chi, \eta, \phi, \vartheta)}{\partial \phi^2} \right] - \\
&- [1 + \varepsilon_{I,V} g_{I,V}(\chi, \eta, \phi, T)] [\tilde{I}_{010}(\chi, \eta, \phi, \vartheta) \tilde{V}_{000}(\chi, \eta, \phi, \vartheta) + \tilde{I}_{000}(\chi, \eta, \phi, \vartheta) \tilde{V}_{010}(\chi, \eta, \phi, \vartheta)]; \\
\frac{\partial \tilde{I}_{001}(\chi, \eta, \phi, \vartheta)}{\partial \vartheta} &= \sqrt{\frac{D_{0I}}{D_{0V}}} \left[\frac{\partial^2 \tilde{I}_{001}(\chi, \eta, \phi, \vartheta)}{\partial \chi^2} + \frac{\partial^2 \tilde{I}_{001}(\chi, \eta, \phi, \vartheta)}{\partial \eta^2} + \frac{\partial^2 \tilde{I}_{001}(\chi, \eta, \phi, \vartheta)}{\partial \phi^2} \right] - \\
&- [1 + \varepsilon_{I,I} g_{I,I}(\chi, \eta, \phi, T)] \tilde{I}_{000}^2(\chi, \eta, \phi, \vartheta) \\
\frac{\partial \tilde{V}_{001}(\chi, \eta, \phi, \vartheta)}{\partial \vartheta} &= \sqrt{\frac{D_{0V}}{D_{0I}}} \left[\frac{\partial^2 \tilde{V}_{001}(\chi, \eta, \phi, \vartheta)}{\partial \chi^2} + \frac{\partial^2 \tilde{V}_{001}(\chi, \eta, \phi, \vartheta)}{\partial \eta^2} + \frac{\partial^2 \tilde{V}_{001}(\chi, \eta, \phi, \vartheta)}{\partial \phi^2} \right] - \\
&- [1 + \varepsilon_{I,I} g_{I,I}(\chi, \eta, \phi, T)] \tilde{V}_{000}^2(\chi, \eta, \phi, \vartheta); \\
\frac{\partial \tilde{I}_{110}(\chi, \eta, \phi, \vartheta)}{\partial \vartheta} &= \sqrt{\frac{D_{0I}}{D_{0V}}} \left[\frac{\partial^2 \tilde{I}_{110}(\chi, \eta, \phi, \vartheta)}{\partial \chi^2} + \frac{\partial^2 \tilde{I}_{110}(\chi, \eta, \phi, \vartheta)}{\partial \eta^2} + \frac{\partial^2 \tilde{I}_{110}(\chi, \eta, \phi, \vartheta)}{\partial \phi^2} \right] + \sqrt{\frac{D_{0I}}{D_{0V}}} \times \\
&\times \left\{ \frac{\partial}{\partial \chi} \left[g_I(\chi, \eta, \phi, T) \frac{\partial \tilde{I}_{010}(\chi, \eta, \phi, \vartheta)}{\partial \chi} \right] + \frac{\partial}{\partial \eta} \left[g_I(\chi, \eta, \phi, T) \frac{\partial \tilde{I}_{010}(\chi, \eta, \phi, \vartheta)}{\partial \eta} \right] + \right.
\end{aligned}$$

$$\begin{aligned}
& + \frac{\partial}{\partial \phi} \left[g_I(\chi, \eta, \phi, T) \frac{\partial \tilde{I}_{010}(\chi, \eta, \phi, \vartheta)}{\partial \phi} \right] \Bigg\} - [1 + \varepsilon_{I,I} g_{I,I}(\chi, \eta, \phi, T)] \times \\
& \times [\tilde{I}_{100}(\chi, \eta, \phi, \vartheta) \tilde{V}_{000}(\chi, \eta, \phi, \vartheta) + \tilde{I}_{000}(\chi, \eta, \phi, \vartheta) \tilde{V}_{100}(\chi, \eta, \phi, \vartheta)] \\
\frac{\partial \tilde{V}_{110}(\chi, \eta, \phi, \vartheta)}{\partial \vartheta} &= \sqrt{\frac{D_{0V}}{D_{0I}}} \left[\frac{\partial^2 \tilde{V}_{110}(\chi, \eta, \phi, \vartheta)}{\partial \chi^2} + \frac{\partial^2 \tilde{V}_{110}(\chi, \eta, \phi, \vartheta)}{\partial \eta^2} + \frac{\partial^2 \tilde{V}_{110}(\chi, \eta, \phi, \vartheta)}{\partial \phi^2} \right] + \\
& + \sqrt{\frac{D_{0V}}{D_{0I}}} \left\{ \frac{\partial}{\partial \chi} \left[g_V(\chi, \eta, \phi, T) \frac{\partial \tilde{V}_{010}(\chi, \eta, \phi, \vartheta)}{\partial \chi} \right] + \frac{\partial}{\partial \eta} \left[g_V(\chi, \eta, \phi, T) \frac{\partial \tilde{V}_{010}(\chi, \eta, \phi, \vartheta)}{\partial \eta} \right] + \right. \\
& + \frac{\partial}{\partial \phi} \left[g_V(\chi, \eta, \phi, T) \frac{\partial \tilde{V}_{010}(\chi, \eta, \phi, \vartheta)}{\partial \phi} \right] \Bigg\} - [1 + \varepsilon_{V,V} g_{V,V}(\chi, \eta, \phi, T)] \times \\
& \times [\tilde{V}_{100}(\chi, \eta, \phi, \vartheta) \tilde{I}_{000}(\chi, \eta, \phi, \vartheta) + \tilde{V}_{000}(\chi, \eta, \phi, \vartheta) \tilde{I}_{100}(\chi, \eta, \phi, \vartheta)]; \\
\frac{\partial \tilde{I}_{002}(\chi, \eta, \phi, \vartheta)}{\partial \vartheta} &= \sqrt{\frac{D_{0I}}{D_{0V}}} \left[\frac{\partial^2 \tilde{I}_{002}(\chi, \eta, \phi, \vartheta)}{\partial \chi^2} + \frac{\partial^2 \tilde{I}_{002}(\chi, \eta, \phi, \vartheta)}{\partial \eta^2} + \frac{\partial^2 \tilde{I}_{002}(\chi, \eta, \phi, \vartheta)}{\partial \phi^2} \right] - \\
& - [1 + \varepsilon_{I,I} g_{I,I}(\chi, \eta, \phi, T)] \tilde{I}_{001}(\chi, \eta, \phi, \vartheta) \tilde{I}_{000}(\chi, \eta, \phi, \vartheta) \\
\frac{\partial \tilde{V}_{002}(\chi, \eta, \phi, \vartheta)}{\partial \vartheta} &= \sqrt{\frac{D_{0V}}{D_{0I}}} \left[\frac{\partial^2 \tilde{V}_{002}(\chi, \eta, \phi, \vartheta)}{\partial \chi^2} + \frac{\partial^2 \tilde{V}_{002}(\chi, \eta, \phi, \vartheta)}{\partial \eta^2} + \frac{\partial^2 \tilde{V}_{002}(\chi, \eta, \phi, \vartheta)}{\partial \phi^2} \right] - \\
& - [1 + \varepsilon_{V,V} g_{V,V}(\chi, \eta, \phi, E)] \tilde{V}_{001}(\chi, \eta, \phi, \vartheta) \tilde{V}_{000}(\chi, \eta, \phi, \vartheta); \\
\frac{\partial \tilde{I}_{101}(\chi, \eta, \phi, \vartheta)}{\partial \vartheta} &= \sqrt{\frac{D_{0I}}{D_{0V}}} \left[\frac{\partial^2 \tilde{I}_{101}(\chi, \eta, \phi, \vartheta)}{\partial \chi^2} + \frac{\partial^2 \tilde{I}_{101}(\chi, \eta, \phi, \vartheta)}{\partial \eta^2} + \frac{\partial^2 \tilde{I}_{101}(\chi, \eta, \phi, \vartheta)}{\partial \phi^2} \right] + \\
& + \sqrt{\frac{D_{0I}}{D_{0V}}} \left\{ \frac{\partial}{\partial \chi} \left[g_I(\chi, \eta, \phi, T) \frac{\partial \tilde{I}_{001}(\chi, \eta, \phi, \vartheta)}{\partial \chi} \right] + \frac{\partial}{\partial \eta} \left[g_I(\chi, \eta, \phi, T) \frac{\partial \tilde{I}_{001}(\chi, \eta, \phi, \vartheta)}{\partial \eta} \right] + \right. \\
& + \frac{\partial}{\partial \phi} \left[g_I(\chi, \eta, \phi, T) \frac{\partial \tilde{I}_{001}(\chi, \eta, \phi, \vartheta)}{\partial \phi} \right] \Bigg\} - [1 + \varepsilon_I g_I(\chi, \eta, \phi, T)] \tilde{I}_{100}(\chi, \eta, \phi, \vartheta) \tilde{V}_{000}(\chi, \eta, \phi, \vartheta) \\
\frac{\partial \tilde{V}_{101}(\chi, \eta, \phi, \vartheta)}{\partial \vartheta} &= \sqrt{\frac{D_{0V}}{D_{0I}}} \left[\frac{\partial^2 \tilde{V}_{101}(\chi, \eta, \phi, \vartheta)}{\partial \chi^2} + \frac{\partial^2 \tilde{V}_{101}(\chi, \eta, \phi, \vartheta)}{\partial \eta^2} + \frac{\partial^2 \tilde{V}_{101}(\chi, \eta, \phi, \vartheta)}{\partial \phi^2} \right] + \\
& + \sqrt{\frac{D_{0V}}{D_{0I}}} \left\{ \frac{\partial}{\partial \chi} \left[g_V(\chi, \eta, \phi, T) \frac{\partial \tilde{V}_{001}(\chi, \eta, \phi, \vartheta)}{\partial \chi} \right] + \frac{\partial}{\partial \eta} \left[g_V(\chi, \eta, \phi, T) \frac{\partial \tilde{V}_{001}(\chi, \eta, \phi, \vartheta)}{\partial \eta} \right] + \right.
\end{aligned}$$

$$\begin{aligned}
& + \frac{\partial}{\partial \phi} \left[g_v(\chi, \eta, \phi, T) \frac{\partial \tilde{V}_{001}(\chi, \eta, \phi, \vartheta)}{\partial \phi} \right] \Bigg\} - [1 + \varepsilon_v g_v(\chi, \eta, \phi, T)] \tilde{I}_{000}(\chi, \eta, \phi, \vartheta) \tilde{V}_{100}(\chi, \eta, \phi, \vartheta); \\
& \frac{\partial \tilde{I}_{011}(\chi, \eta, \phi, \vartheta)}{\partial \vartheta} = \sqrt{\frac{D_{0I}}{D_{0V}}} \left[\frac{\partial^2 \tilde{I}_{011}(\chi, \eta, \phi, \vartheta)}{\partial \chi^2} + \frac{\partial^2 \tilde{I}_{011}(\chi, \eta, \phi, \vartheta)}{\partial \eta^2} + \frac{\partial^2 \tilde{I}_{011}(\chi, \eta, \phi, \vartheta)}{\partial \phi^2} \right] - \tilde{I}_{010}(\chi, \eta, \phi, \vartheta) \times \\
& \times [1 + \varepsilon_{I,I} g_{I,I}(\chi, \eta, \phi, T)] \tilde{I}_{000}(\chi, \eta, \phi, \vartheta) - [1 + \varepsilon_{I,V} g_{I,V}(\chi, \eta, \phi, T)] \tilde{I}_{001}(\chi, \eta, \phi, \vartheta) \tilde{V}_{000}(\chi, \eta, \phi, \vartheta) \\
& \frac{\partial \tilde{V}_{011}(\chi, \eta, \phi, \vartheta)}{\partial \vartheta} = \sqrt{\frac{D_{0V}}{D_{0I}}} \left[\frac{\partial^2 \tilde{V}_{011}(\chi, \eta, \phi, \vartheta)}{\partial \chi^2} + \frac{\partial^2 \tilde{V}_{011}(\chi, \eta, \phi, \vartheta)}{\partial \eta^2} + \frac{\partial^2 \tilde{V}_{011}(\chi, \eta, \phi, \vartheta)}{\partial \phi^2} \right] - \tilde{V}_{010}(\chi, \eta, \phi, \vartheta) \times \\
& \times [1 + \varepsilon_{V,V} g_{V,V}(\chi, \eta, \phi, T)] \tilde{V}_{000}(\chi, \eta, \phi, \vartheta) - [1 + \varepsilon_{I,V} g_{I,V}(\chi, \eta, \phi, T)] \tilde{I}_{000}(\chi, \eta, \phi, \vartheta) \tilde{V}_{001}(\chi, \eta, \phi, \vartheta); \\
& \left. \frac{\partial \tilde{\rho}_{ijk}(\chi, \eta, \phi, \vartheta)}{\partial \chi} \right|_{\chi=0} = 0, \quad \left. \frac{\partial \tilde{\rho}_{ijk}(\chi, \eta, \phi, \vartheta)}{\partial \chi} \right|_{\chi=1} = 0, \quad \left. \frac{\partial \tilde{\rho}_{ijk}(\chi, \eta, \phi, \vartheta)}{\partial \eta} \right|_{\eta=0} = 0, \\
& \left. \frac{\partial \tilde{\rho}_{ijk}(\chi, \eta, \phi, \vartheta)}{\partial \eta} \right|_{\eta=1} = 0, \\
& \left. \frac{\partial \tilde{\rho}_{ijk}(\chi, \eta, \phi, \vartheta)}{\partial \phi} \right|_{\phi=0} = 0, \quad \left. \frac{\partial \tilde{\rho}_{ijk}(\chi, \eta, \phi, \vartheta)}{\partial \phi} \right|_{\phi=1} = 0 \quad (i \geq 0, j \geq 0, k \geq 0); \\
& \tilde{\rho}_{000}(\chi, \eta, \phi, 0) = f_\rho(\chi, \eta, \phi) / \rho^*, \quad \tilde{\rho}_{ijk}(\chi, \eta, \phi, 0) = 0 \quad (i \geq 1, j \geq 1, k \geq 1).
\end{aligned}$$

Solutions of the above equations could be written as

$$\begin{aligned}
& \tilde{\rho}_{000}(\chi, \eta, \phi, \vartheta) = \frac{1}{L} + \frac{2}{L} \sum_{n=1}^{\infty} F_{n\rho} c(\chi) c(\eta) c(\phi) e_{n\rho}(\vartheta), \\
& \text{where } F_{n\rho} = \frac{1}{\rho^*} \int_0^1 \cos(\pi n u) \int_0^1 \cos(\pi n v) \int_0^1 \cos(\pi n w) f_{n\rho}(u, v, w) d w d v d u, \quad c_n(\chi) = \cos(\pi n \chi), \\
& e_{nI}(\vartheta) = \exp\left(-\pi^2 n^2 \vartheta \sqrt{D_{0V}/D_{0I}}\right), \quad e_{nV}(\vartheta) = \exp\left(-\pi^2 n^2 \vartheta \sqrt{D_{0I}/D_{0V}}\right); \\
& \tilde{I}_{i00}(\chi, \eta, \phi, \vartheta) = -2\pi \sqrt{\frac{D_{0I}}{D_{0V}}} \sum_{n=1}^{\infty} n c_n(\chi) c(\eta) c(\phi) e_{nI}(\vartheta) \int_0^{\vartheta} e_{nI}(-\tau) \int_0^1 s_n(u) \int_0^1 c_n(v) \int_0^1 \frac{\partial \tilde{I}_{i-100}(u, v, w, \tau)}{\partial u} \times \\
& \times c_n(w) g_I(u, v, w, T) d w d v d u d \tau - 2\pi \sqrt{\frac{D_{0I}}{D_{0V}}} \sum_{n=1}^{\infty} n c_n(\chi) c(\eta) c(\phi) e_{nI}(\vartheta) \int_0^{\vartheta} e_{nI}(-\tau) \int_0^1 c_n(u) \int_0^1 s_n(v) \times \\
& \times \int_0^1 c_n(w) g_I(u, v, w, T) \frac{\partial \tilde{I}_{i-100}(u, v, w, \tau)}{\partial v} d w d v d u d \tau - 2\pi \sqrt{\frac{D_{0I}}{D_{0V}}} \sum_{n=1}^{\infty} n c_n(\chi) c(\eta) c(\phi) e_{nI}(\vartheta) \int_0^{\vartheta} e_{nI}(-\tau) \times \\
& \times \int_0^1 c_n(u) \int_0^1 c_n(v) \int_0^1 s_n(w) g_I(u, v, w, T) \frac{\partial \tilde{I}_{i-100}(u, v, w, \tau)}{\partial w} d w d v d u d \tau, \quad i \geq 1,
\end{aligned}$$

$$\begin{aligned}
\tilde{V}_{i00}(\chi, \eta, \phi, \vartheta) = & -2\pi \sqrt{\frac{D_{0V}}{D_{0I}}} \sum_{n=1}^{\infty} n c_n(\chi) c_n(\eta) c_n(\phi) e_{nV}(\vartheta) \int_0^{\vartheta} e_{nI}(-\tau) \int_0^1 s_n(u) \int_0^1 c_n(v) \int_0^1 g_V(u, v, w, T) \times \\
& \times c_n(w) \frac{\partial \tilde{V}_{i-100}(u, \tau)}{\partial u} d w d v d u d \tau - \sqrt{\frac{D_{0V}}{D_{0I}}} \sum_{n=1}^{\infty} n c_n(\chi) c_n(\eta) c_n(\phi) e_{nV}(\vartheta) \int_0^{\vartheta} e_{nI}(-\tau) \int_0^1 c_n(u) \int_0^1 s_n(v) \times \\
& \times 2\pi \int_0^1 c_n(w) g_V(u, v, w, T) \frac{\partial \tilde{V}_{i-100}(u, \tau)}{\partial v} d w d v d u d \tau - 2\pi \sqrt{\frac{D_{0V}}{D_{0I}}} \sum_{n=1}^{\infty} n c_n(\chi) c_n(\eta) c_n(\phi) e_{nV}(\vartheta) \times \\
& \times \int_0^{\vartheta} e_{nI}(-\tau) \int_0^1 c_n(u) \int_0^1 c_n(v) \int_0^1 s_n(w) g_V(u, v, w, T) \frac{\partial \tilde{V}_{i-100}(u, \tau)}{\partial w} d w d v d u d \tau, \quad i \geq l,
\end{aligned}$$

where $s_n(\chi) = \sin(\pi n \chi)$;

$$\begin{aligned}
\tilde{\rho}_{010}(\chi, \eta, \phi, \vartheta) = & -2 \sum_{n=1}^{\infty} c_n(\chi) c_n(\eta) c_n(\phi) e_{n\rho}(\vartheta) \int_0^{\vartheta} e_{n\rho}(-\tau) \int_0^1 c_n(u) \int_0^1 c_n(v) \int_0^1 c_n(w) \times \\
& \times [1 + \varepsilon_{I,V} g_{I,V}(u, v, w, T)] \tilde{I}_{000}(u, v, w, \tau) \tilde{V}_{000}(u, v, w, \tau) d w d v d u d \tau; \\
\tilde{\rho}_{020}(\chi, \eta, \phi, \vartheta) = & -2 \sqrt{\frac{D_{0I}}{D_{0V}}} \sum_{n=1}^{\infty} c_n(\chi) c_n(\eta) c_n(\phi) e_{n\rho}(\vartheta) \int_0^{\vartheta} e_{n\rho}(-\tau) \int_0^1 c_n(u) \int_0^1 c_n(v) \int_0^1 c_n(w) [1 + \varepsilon_{I,V} \times \\
& \times g_{I,V}(u, v, w, T)] [\tilde{I}_{010}(u, v, w, \tau) \tilde{V}_{000}(u, v, w, \tau) + \tilde{I}_{000}(u, v, w, \tau) \tilde{V}_{010}(u, v, w, \tau)] d w d v d u d \tau; \\
\tilde{\rho}_{001}(\chi, \eta, \phi, \vartheta) = & -2 \sum_{n=1}^{\infty} c_n(\chi) c_n(\eta) c_n(\phi) e_{n\rho}(\vartheta) \int_0^{\vartheta} e_{n\rho}(-\tau) \int_0^1 c_n(u) \int_0^1 c_n(v) \int_0^1 c_n(w) \times \\
& \times [1 + \varepsilon_{\rho,\rho} g_{\rho,\rho}(u, v, w, T)] \tilde{\rho}_{000}^2(u, v, w, \tau) d w d v d u d \tau; \\
\tilde{\rho}_{002}(\chi, \eta, \phi, \vartheta) = & -2 \sum_{n=1}^{\infty} c_n(\chi) c_n(\eta) c_n(\phi) e_{n\rho}(\vartheta) \int_0^{\vartheta} e_{n\rho}(-\tau) \int_0^1 c_n(u) \int_0^1 c_n(v) \int_0^1 c_n(w) \times \\
& \times [1 + \varepsilon_{\rho,\rho} g_{\rho,\rho}(u, v, w, T)] \tilde{\rho}_{001}(u, v, w, \tau) \tilde{\rho}_{000}(u, v, w, \tau) d w d v d u d \tau; \\
\tilde{I}_{110}(\chi, \eta, \phi, \vartheta) = & -2\pi \sqrt{\frac{D_{0I}}{D_{0V}}} \sum_{n=1}^{\infty} n c_n(\chi) c_n(\eta) c_n(\phi) e_{nI}(\vartheta) \int_0^{\vartheta} e_{nI}(-\tau) \int_0^1 s_n(u) \int_0^1 c_n(v) \int_0^1 c_n(u) \times \\
& \times g_I(u, v, w, T) \frac{\partial \tilde{I}_{i-100}(u, v, w, \tau)}{\partial u} d w d v d u d \tau - 2\pi \sqrt{\frac{D_{0I}}{D_{0V}}} \sum_{n=1}^{\infty} n c_n(\chi) c_n(\eta) c_n(\phi) e_{nI}(\vartheta) \times \\
& \times \int_0^{\vartheta} e_{nI}(-\tau) \int_0^1 c_n(u) \int_0^1 s_n(v) \int_0^1 c_n(u) g_I(u, v, w, T) \frac{\partial \tilde{I}_{i-100}(u, v, w, \tau)}{\partial v} d w d v d u d \tau - 2\pi \sqrt{\frac{D_{0I}}{D_{0V}}} \times \\
& \times \sum_{n=1}^{\infty} n e_{nI}(\vartheta) \int_0^{\vartheta} e_{nI}(-\tau) \int_0^1 c_n(u) \int_0^1 c_n(v) \int_0^1 s_n(u) g_I(u, v, w, T) \frac{\partial \tilde{I}_{i-100}(u, v, w, \tau)}{\partial w} d w d v d u d \tau \times \\
& \times c_n(\chi) c_n(\eta) c_n(\phi) - 2 \sum_{n=1}^{\infty} c_n(\chi) e_{nI}(\vartheta) c_n(\eta) c_n(\phi) \int_0^{\vartheta} e_{nI}(-\tau) \int_0^1 c_n(u) \int_0^1 c_n(v) \int_0^1 c_n(v) [1 + \varepsilon_{I,V} \times
\end{aligned}$$

$$\begin{aligned}
 & \times g_{I,V}(u, v, w, T) \left[\tilde{I}_{100}(u, v, w, \tau) \tilde{V}_{000}(u, v, w, \tau) + \tilde{I}_{000}(u, v, w, \tau) \tilde{V}_{100}(u, v, w, \tau) \right] d w d v d u d \tau \\
 & \tilde{V}_{110}(\chi, \eta, \phi, \vartheta) = -2\pi \sqrt{\frac{D_{0V}}{D_{0I}}} \sum_{n=1}^{\infty} n c_n(\chi) c_n(\eta) c_n(\phi) e_{nV}(\vartheta) \int_0^{\vartheta} e_{nV}(-\tau) \int_0^1 s_n(u) \int_0^1 c_n(v) \int_0^1 c_n(u) \times \\
 & \times g_V(u, v, w, T) \frac{\partial \tilde{V}_{i-100}(u, v, w, \tau)}{\partial u} d w d v d u d \tau - 2\pi \sqrt{\frac{D_{0V}}{D_{0I}}} \sum_{n=1}^{\infty} n c_n(\chi) c_n(\eta) c_n(\phi) e_{nV}(\vartheta) \times \\
 & \times \int_0^{\vartheta} e_{nV}(-\tau) \int_0^1 c_n(u) \int_0^1 s_n(v) \int_0^1 c_n(u) g_V(u, v, w, T) \frac{\partial \tilde{V}_{i-100}(u, v, w, \tau)}{\partial v} d w d v d u d \tau - 2\pi \sqrt{\frac{D_{0V}}{D_{0I}}} \times \\
 & \times \sum_{n=1}^{\infty} n e_{nV}(\vartheta) \int_0^{\vartheta} e_{nV}(-\tau) \int_0^1 c_n(u) \int_0^1 c_n(v) \int_0^1 s_n(u) g_V(u, v, w, T) \frac{\partial \tilde{V}_{i-100}(u, v, w, \tau)}{\partial w} d w d v d u d \tau \times \\
 & \times c_n(\chi) c_n(\eta) c_n(\phi) - 2 \sum_{n=1}^{\infty} c_n(\chi) e_{nI}(\vartheta) c_n(\eta) c_n(\phi) \int_0^{\vartheta} e_{nV}(-\tau) \int_0^1 c_n(u) \int_0^1 c_n(v) \int_0^1 [1 + \varepsilon_{I,V} g_{I,V}(u, v, w, T)] \times \\
 & \times c_n(w) \left[\tilde{I}_{100}(u, v, w, \tau) \tilde{V}_{000}(u, v, w, \tau) + \tilde{I}_{000}(u, v, w, \tau) \tilde{V}_{100}(u, v, w, \tau) \right] d w d v d u d \tau ; \\
 & \tilde{I}_{101}(\chi, \eta, \phi, \vartheta) = -2\pi \sqrt{\frac{D_{0I}}{D_{0V}}} \sum_{n=1}^{\infty} n c_n(\chi) c_n(\eta) c_n(\phi) e_{nI}(\vartheta) \int_0^{\vartheta} e_{nI}(-\tau) \int_0^1 s_n(u) \int_0^1 c_n(v) \int_0^1 g_I(u, v, w, T) \times \\
 & \times c_n(w) \frac{\partial \tilde{I}_{001}(u, v, w, \tau)}{\partial u} d w d v d u d \tau - 2\pi \sqrt{\frac{D_{0I}}{D_{0V}}} \sum_{n=1}^{\infty} n c_n(\chi) c_n(\eta) c_n(\phi) e_{nI}(\vartheta) \times \\
 & \times \int_0^1 s_n(v) \int_0^1 c_n(w) g_I(u, v, w, T) \frac{\partial \tilde{I}_{001}(u, v, w, \tau)}{\partial v} d w d v d u d \tau - 2\pi \sqrt{\frac{D_{0I}}{D_{0V}}} \sum_{n=1}^{\infty} n e_{nI}(\vartheta) c_n(\chi) c_n(\eta) c_n(\phi) \times \\
 & \times \int_0^{\vartheta} e_{nI}(-\tau) \int_0^1 c_n(u) \int_0^1 c_n(v) \int_0^1 s_n(w) g_I(u, v, w, T) \frac{\partial \tilde{I}_{001}(u, v, w, \tau)}{\partial w} d w d v d u d \tau - 2 \sum_{n=1}^{\infty} c_n(\chi) c_n(\eta) c_n(\phi) \times \\
 & \times e_{nI}(\vartheta) \int_0^{\vartheta} e_{nI}(-\tau) \int_0^1 c_n(u) \int_0^1 c_n(v) \int_0^1 c_n(w) [1 + \varepsilon_{I,V} g_{I,V}(u, v, w, T)] \tilde{I}_{100}(u, v, w, \tau) \tilde{V}_{000}(u, v, w, \tau) d w d v d u d \tau \\
 & \tilde{V}_{101}(\chi, \eta, \phi, \vartheta) = -2\pi \sqrt{\frac{D_{0V}}{D_{0I}}} \sum_{n=1}^{\infty} n c_n(\chi) c_n(\eta) c_n(\phi) e_{nV}(\vartheta) \int_0^{\vartheta} e_{nV}(-\tau) \int_0^1 s_n(u) \int_0^1 c_n(v) \int_0^1 g_V(u, v, w, T) \times \\
 & \times c_n(w) \frac{\partial \tilde{V}_{001}(u, v, w, \tau)}{\partial u} d w d v d u d \tau - 2\pi \sqrt{\frac{D_{0V}}{D_{0I}}} \sum_{n=1}^{\infty} n c_n(\chi) c_n(\eta) c_n(\phi) e_{nI}(\vartheta) \int_0^{\vartheta} e_{nV}(-\tau) \int_0^1 c_n(u) \times \\
 & \times \int_0^1 s_n(v) \int_0^1 c_n(w) g_I(u, v, w, T) \frac{\partial \tilde{I}_{001}(u, v, w, \tau)}{\partial v} d w d v d u d \tau - 2\pi \sqrt{\frac{D_{0I}}{D_{0V}}} \sum_{n=1}^{\infty} n e_{nI}(\vartheta) c_n(\chi) c_n(\eta) c_n(\phi) \times \\
 & \times \int_0^{\vartheta} e_{nV}(-\tau) \int_0^1 c_n(u) \int_0^1 c_n(v) \int_0^1 s_n(w) g_V(u, v, w, T) \frac{\partial \tilde{V}_{001}(u, v, w, \tau)}{\partial w} d w d v d u d \tau - 2 \sum_{n=1}^{\infty} c_n(\chi) c_n(\eta) c_n(\phi) \times
 \end{aligned}$$

$$\begin{aligned}
& \times e_{nV}(\vartheta) \int_0^{\vartheta} e_{nV}(-\tau) \int_0^1 c_n(u) \int_0^1 c_n(v) \int_0^1 c_n(w) [1 + \varepsilon_{I,V} g_{I,V}(u, v, w, T)] \tilde{I}_{100}(u, v, w, \tau) \tilde{V}_{000}(u, v, w, \tau) dw dv du d\tau : \\
& \tilde{I}_{011}(\chi, \eta, \phi, \vartheta) = -2 \sum_{n=1}^{\infty} c_n(\chi) c_n(\eta) c_n(\phi) e_{nI}(\vartheta) \int_0^{\vartheta} e_{nI}(-\tau) \int_0^1 c_n(u) \int_0^1 c_n(v) \int_0^1 c_n(w) \{ \tilde{I}_{000}(u, v, w, \tau) \times \\
& \times [1 + \varepsilon_{I,I} g_{I,I}(u, v, w, T)] \tilde{I}_{010}(u, v, w, \tau) + [1 + \varepsilon_{I,V} g_{I,V}(u, v, w, T)] \tilde{I}_{001}(u, v, w, \tau) \tilde{V}_{000}(u, v, w, \tau) \} dw dv du d\tau \\
& \tilde{V}_{011}(\chi, \eta, \phi, \vartheta) = -2 \sum_{n=1}^{\infty} c_n(\chi) c_n(\eta) c_n(\phi) e_{nV}(\vartheta) \int_0^{\vartheta} e_{nV}(-\tau) \int_0^1 c_n(u) \int_0^1 c_n(v) \int_0^1 c_n(w) \{ \tilde{I}_{000}(u, v, w, \tau) \times \\
& \times [1 + \varepsilon_{I,I} g_{I,I}(u, v, w, T)] \tilde{I}_{010}(u, v, w, \tau) + [1 + \varepsilon_{I,V} g_{I,V}(u, v, w, T)] \tilde{I}_{001}(u, v, w, \tau) \tilde{V}_{000}(u, v, w, \tau) \} dw dv du d\tau .
\end{aligned}$$

Equations for functions $\Phi_{\alpha}(x, y, z, t)$, $i \geq 0$ to describe concentrations of simplest complexes of radiation defects.

$$\begin{aligned}
\frac{\partial \Phi_{I0}(x, y, z, t)}{\partial t} &= D_{0\Phi I} \left[\frac{\partial^2 \Phi_{I0}(x, y, z, t)}{\partial x^2} + \frac{\partial^2 \Phi_{I0}(x, y, z, t)}{\partial y^2} + \frac{\partial^2 \Phi_{I0}(x, y, z, t)}{\partial z^2} \right] + \\
&+ k_{I,I}(x, y, z, T) I^2(x, y, z, t) - k_I(x, y, z, T) I(x, y, z, t) \\
\frac{\partial \Phi_{V0}(x, y, z, t)}{\partial t} &= D_{0\Phi V} \left[\frac{\partial^2 \Phi_{V0}(x, y, z, t)}{\partial x^2} + \frac{\partial^2 \Phi_{V0}(x, y, z, t)}{\partial y^2} + \frac{\partial^2 \Phi_{V0}(x, y, z, t)}{\partial z^2} \right] + \\
&+ k_{V,V}(x, y, z, T) V^2(x, y, z, t) - k_V(x, y, z, T) V(x, y, z, t); \\
\frac{\partial \Phi_{Ii}(x, y, z, t)}{\partial t} &= D_{0\Phi I} \left[\frac{\partial^2 \Phi_{Ii}(x, y, z, t)}{\partial x^2} + \frac{\partial^2 \Phi_{Ii}(x, y, z, t)}{\partial y^2} + \frac{\partial^2 \Phi_{Ii}(x, y, z, t)}{\partial z^2} \right] + \\
&+ D_{0\Phi I} \left\{ \frac{\partial}{\partial x} \left[g_{\Phi I}(x, y, z, T) \frac{\partial \Phi_{Ii-1}(x, y, z, t)}{\partial x} \right] + \frac{\partial}{\partial y} \left[g_{\Phi I}(x, y, z, T) \frac{\partial \Phi_{Ii-1}(x, y, z, t)}{\partial y} \right] + \right. \\
&\quad \left. + \frac{\partial}{\partial z} \left[g_{\Phi I}(x, y, z, T) \frac{\partial \Phi_{Ii-1}(x, y, z, t)}{\partial z} \right] \right\}, i \geq 1, \\
\frac{\partial \Phi_{Vi}(x, y, z, t)}{\partial t} &= D_{0\Phi V} \left[\frac{\partial^2 \Phi_{Vi}(x, y, z, t)}{\partial x^2} + \frac{\partial^2 \Phi_{Vi}(x, y, z, t)}{\partial y^2} + \frac{\partial^2 \Phi_{Vi}(x, y, z, t)}{\partial z^2} \right] + \\
&+ D_{0\Phi V} \left\{ \frac{\partial}{\partial x} \left[g_{\Phi V}(x, y, z, T) \frac{\partial \Phi_{Vi-1}(x, y, z, t)}{\partial x} \right] + \frac{\partial}{\partial y} \left[g_{\Phi V}(x, y, z, T) \frac{\partial \Phi_{Vi-1}(x, y, z, t)}{\partial y} \right] + \right. \\
&\quad \left. + \frac{\partial}{\partial z} \left[g_{\Phi V}(x, y, z, T) \frac{\partial \Phi_{Vi-1}(x, y, z, t)}{\partial z} \right] \right\}, i \geq 1;
\end{aligned}$$

Boundary and initial conditions for the functions takes the form

$$\left. \frac{\partial \Phi_{\rho i}(x, y, z, t)}{\partial x} \right|_{x=0} = 0, \quad \left. \frac{\partial \Phi_{\rho i}(x, y, z, t)}{\partial x} \right|_{x=L_x} = 0, \quad \left. \frac{\partial \Phi_{\rho i}(x, y, z, t)}{\partial y} \right|_{y=0} = 0, \quad \left. \frac{\partial \Phi_{\rho i}(x, y, z, t)}{\partial y} \right|_{y=L_y} = 0,$$

$$\left. \frac{\partial \Phi_{\rho i}(x, y, z, t)}{\partial z} \right|_{z=0} = 0, \quad \left. \frac{\partial \Phi_{\rho i}(x, y, z, t)}{\partial z} \right|_{z=L_z} = 0, \quad i \geq 0; \quad \Phi_{\rho 0}(x, y, z, 0) = f_{\Phi \rho}(x, y, z),$$

$$\Phi_{\rho i}(x, y, z, 0) = 0, \quad i \geq 1.$$

Solutions of the above equations could be written as

$$\Phi_{\rho 0}(x, y, z, t) = \frac{1}{L_x L_y L_z} + \frac{2}{L_x L_y L_z} \sum_{n=1}^{\infty} F_{n\Phi \rho} c_n(x) c_n(y) c_n(z) e_{n\Phi \rho}(t) + \frac{2}{L} \sum_{n=1}^{\infty} n c_n(x) c_n(y) c_n(z) \times$$

$$\times e_{\Phi \rho n}(t) \int_0^t e_{\Phi \rho n}(-\tau) \int_0^{L_x} c_n(u) \int_0^{L_y} c_n(v) \int_0^{L_z} c_n(w) [k_{I, I}(u, v, w, T) I^2(u, v, w, \tau) -$$

$$- k_I(u, v, w, T) I(u, v, w, \tau)] dw dv du d\tau,$$

where $F_{n\Phi \rho} = \int_0^{L_x} c_n(u) \int_0^{L_y} c_n(v) \int_0^{L_z} c_n(w) f_{\Phi \rho}(u, v, w) dw dv du$, $e_{n\Phi \rho}(t) = \exp[-\pi^2 n^2 D_{0\Phi \rho} t (L_x^2 + L_y^2 + L_z^2)]$, $c_n(x) = \cos(\pi n x / L_x)$;

$$\Phi_{\rho i}(x, y, z, t) = -\frac{2\pi}{L_x^2 L_y L_z} \sum_{n=1}^{\infty} n c_n(x) c_n(y) c_n(z) e_{\Phi \rho n}(t) \int_0^t e_{\Phi \rho n}(-\tau) \int_0^{L_x} s_n(u) \int_0^{L_y} c_n(v) \int_0^{L_z} g_{\Phi \rho}(u, v, w, T) \times$$

$$\times c_n(w) \frac{\partial \Phi_{I \rho^{i-1}}(u, v, w, \tau)}{\partial u} dw dv du d\tau - \frac{2\pi}{L_x L_y L_z^2} \sum_{n=1}^{\infty} n c_n(x) c_n(y) c_n(z) e_{\Phi \rho n}(t) \int_0^t e_{\Phi \rho n}(-\tau) \times$$

$$\times \int_0^t e_{\Phi \rho n}(-\tau) \int_0^{L_x} c_n(u) \int_0^{L_y} s_n(v) \int_0^{L_z} c_n(w) g_{\Phi \rho}(u, v, w, T) \frac{\partial \Phi_{I \rho^{i-1}}(u, v, w, \tau)}{\partial v} dw dv du d\tau - \frac{2\pi}{L_x L_y L_z^2} \sum_{n=1}^{\infty} n \times$$

$$\times e_{\Phi \rho n}(t) \int_0^t e_{\Phi \rho n}(-\tau) \int_0^{L_x} c_n(u) \int_0^{L_y} c_n(v) \int_0^{L_z} s_n(w) \frac{\partial \Phi_{I \rho^{i-1}}(u, v, w, \tau)}{\partial w} g_{\Phi \rho}(u, v, w, T) dw dv du d\tau \times$$

$$\times c_n(x) c_n(y) c_n(z), \quad i \geq 1,$$

where $s_n(x) = \sin(\pi n x / L_x)$.

Equations for the functions $C_{ij}(x, y, z, t)$ ($i \geq 0, j \geq 0$), boundary and initial conditions could be written as

$$\frac{\partial C_{00}(x, y, z, t)}{\partial t} = D_{0L} \frac{\partial^2 C_{00}(x, y, z, t)}{\partial x^2} + D_{0L} \frac{\partial^2 C_{00}(x, y, z, t)}{\partial y^2} + D_{0L} \frac{\partial^2 C_{00}(x, y, z, t)}{\partial z^2};$$

$$\frac{\partial C_{i0}(x, y, z, t)}{\partial t} = D_{0L} \left[\frac{\partial^2 C_{i0}(x, y, z, t)}{\partial x^2} + \frac{\partial^2 C_{i0}(x, y, z, t)}{\partial y^2} + \frac{\partial^2 C_{i0}(x, y, z, t)}{\partial z^2} \right] +$$

$$+ D_{0L} \frac{\partial}{\partial x} \left[g_L(x, y, z, T) \frac{\partial C_{i-10}(x, y, z, t)}{\partial x} \right] + D_{0L} \frac{\partial}{\partial y} \left[g_L(x, y, z, T) \frac{\partial C_{i-10}(x, y, z, t)}{\partial y} \right] +$$

$$+ D_{0L} \frac{\partial}{\partial z} \left[g_L(x, y, z, T) \frac{\partial C_{i-10}(x, y, z, t)}{\partial z} \right], \quad i \geq 1;$$

$$\begin{aligned}
\frac{\partial C_{01}(x, y, z, t)}{\partial t} &= D_{0L} \frac{\partial^2 C_{01}(x, y, z, t)}{\partial x^2} + D_{0L} \frac{\partial^2 C_{01}(x, y, z, t)}{\partial y^2} + D_{0L} \frac{\partial^2 C_{01}(x, y, z, t)}{\partial z^2} + \\
&+ D_{0L} \frac{\partial}{\partial x} \left[\frac{C_{00}^\gamma(x, y, z, t)}{P^\gamma(x, y, z, T)} \frac{\partial C_{00}(x, y, z, t)}{\partial x} \right] + D_{0L} \frac{\partial}{\partial y} \left[\frac{C_{00}^\gamma(x, y, z, t)}{P^\gamma(x, y, z, T)} \frac{\partial C_{00}(x, y, z, t)}{\partial y} \right] + \\
&+ D_{0L} \frac{\partial}{\partial z} \left[\frac{C_{00}^\gamma(x, y, z, t)}{P^\gamma(x, y, z, T)} \frac{\partial C_{00}(x, y, z, t)}{\partial z} \right]; \\
\frac{\partial C_{02}(x, y, z, t)}{\partial t} &= D_{0L} \frac{\partial^2 C_{02}(x, y, z, t)}{\partial x^2} + D_{0L} \frac{\partial^2 C_{02}(x, y, z, t)}{\partial y^2} + D_{0L} \frac{\partial^2 C_{02}(x, y, z, t)}{\partial z^2} + \\
&+ D_{0L} \left\{ \frac{\partial}{\partial x} \left[C_{01}(x, y, z, t) \frac{C_{00}^{\gamma-1}(x, y, z, t)}{P^\gamma(x, y, z, T)} \frac{\partial C_{00}(x, y, z, t)}{\partial x} \right] + \frac{\partial}{\partial y} \left[C_{01}(x, y, z, t) \frac{C_{00}^{\gamma-1}(x, y, z, t)}{P^\gamma(x, y, z, T)} \times \right. \right. \\
&\quad \times \left. \frac{\partial C_{00}(x, y, z, t)}{\partial y} \right] + \frac{\partial}{\partial z} \left[C_{01}(x, y, z, t) \frac{C_{00}^{\gamma-1}(x, y, z, t)}{P^\gamma(x, y, z, T)} \frac{\partial C_{00}(x, y, z, t)}{\partial z} \right] \Big\} + \\
&\times \frac{\partial C_{00}(x, y, z, t)}{\partial y} \Big] + \frac{\partial}{\partial z} \left[C_{01}(x, y, z, t) \frac{C_{00}^{\gamma-1}(x, y, z, t)}{P^\gamma(x, y, z, T)} \frac{\partial C_{00}(x, y, z, t)}{\partial z} \right] \Big\} + D_{0L} \left\{ \frac{\partial}{\partial x} \left[\frac{C_{00}^\gamma(x, y, z, t)}{P^\gamma(x, y, z, T)} \times \right. \right. \\
&\times \left. \frac{\partial C_{01}(x, y, z, t)}{\partial x} \right] + \frac{\partial}{\partial y} \left[\frac{C_{00}^\gamma(x, y, z, t)}{P^\gamma(x, y, z, T)} \frac{\partial C_{01}(x, y, z, t)}{\partial y} \right] + \frac{\partial}{\partial z} \left[\frac{C_{00}^\gamma(x, y, z, t)}{P^\gamma(x, y, z, T)} \frac{\partial C_{01}(x, y, z, t)}{\partial z} \right] \Big\}; \\
\frac{\partial C_{11}(x, y, z, t)}{\partial t} &= D_{0L} \frac{\partial^2 C_{11}(x, y, z, t)}{\partial x^2} + D_{0L} \frac{\partial^2 C_{11}(x, y, z, t)}{\partial y^2} + D_{0L} \frac{\partial^2 C_{11}(x, y, z, t)}{\partial z^2} + \\
&+ \left\{ \frac{\partial}{\partial x} \left[C_{10}(x, y, z, t) \frac{C_{00}^{\gamma-1}(x, y, z, t)}{P^\gamma(x, y, z, T)} \frac{\partial C_{00}(x, y, z, t)}{\partial x} \right] + \frac{\partial}{\partial y} \left[C_{10}(x, y, z, t) \frac{C_{00}^{\gamma-1}(x, y, z, t)}{P^\gamma(x, y, z, T)} \times \right. \right. \\
&\quad \times \left. \frac{\partial C_{00}(x, y, z, t)}{\partial y} \right] + \frac{\partial}{\partial z} \left[C_{10}(x, y, z, t) \frac{C_{00}^{\gamma-1}(x, y, z, t)}{P^\gamma(x, y, z, T)} \frac{\partial C_{00}(x, y, z, t)}{\partial z} \right] \Big\} D_{0L} + \\
&+ D_{0L} \left\{ \frac{\partial}{\partial x} \left[\frac{C_{00}^\gamma(x, y, z, t)}{P^\gamma(x, y, z, T)} \frac{\partial C_{10}(x, y, z, t)}{\partial x} \right] + \frac{\partial}{\partial y} \left[\frac{C_{00}^\gamma(x, y, z, t)}{P^\gamma(x, y, z, T)} \frac{\partial C_{10}(x, y, z, t)}{\partial y} \right] + \right. \\
&+ \left. \frac{\partial}{\partial z} \left[\frac{C_{00}^\gamma(x, y, z, t)}{P^\gamma(x, y, z, T)} \frac{\partial C_{10}(x, y, z, t)}{\partial z} \right] \right\} + D_{0L} \left\{ \frac{\partial}{\partial x} \left[g_L(x, y, z, T) \frac{\partial C_{01}(x, y, z, t)}{\partial x} \right] + \right. \\
&+ \left. \frac{\partial}{\partial y} \left[g_L(x, y, z, T) \frac{\partial C_{01}(x, y, z, t)}{\partial y} \right] + \frac{\partial}{\partial z} \left[g_L(x, y, z, T) \frac{\partial C_{01}(x, y, z, t)}{\partial z} \right] \right\};
\end{aligned}$$

$$\left. \frac{\partial C_{ij}(x, y, z, t)}{\partial x} \right|_{x=0} = 0, \left. \frac{\partial C_{ij}(x, y, z, t)}{\partial x} \right|_{x=L_x} = 0, \left. \frac{\partial C_{ij}(x, y, z, t)}{\partial y} \right|_{y=0} = 0, \left. \frac{\partial C_{ij}(x, y, z, t)}{\partial y} \right|_{y=L_y} = 0,$$

$$\left. \frac{\partial C_{ij}(x, y, z, t)}{\partial z} \right|_{z=0} = 0, \left. \frac{\partial C_{ij}(x, y, z, t)}{\partial z} \right|_{z=L_z} = 0, i \geq 0, j \geq 0;$$

$$C_{00}(x, y, z, 0) = f_C(x, y, z), C_{ij}(x, y, z, 0) = 0, i \geq 1, j \geq 1.$$

Functions $C_{ij}(x, y, z, t)$ ($i \geq 0, j \geq 0$) could be approximated by the following series during solutions of the above equations

$$C_{00}(x, y, z, t) = \frac{F_{0C}}{L_x L_y L_z} + \frac{2}{L_x L_y L_z} \sum_{n=1}^{\infty} F_{nC} c_n(x) c_n(y) c_n(z) e_{nC}(t).$$

Here

$$e_{nC}(t) = \exp \left[-\pi^2 n^2 D_{0C} t \left(\frac{1}{L_x^2} + \frac{1}{L_y^2} + \frac{1}{L_z^2} \right) \right], F_{nC} = \int_0^{L_x} c_n(u) \int_0^{L_y} c_n(v) \int_0^{L_z} f_C(u, v, w) c_n(w) dw dv du;$$

$$C_{i0}(x, y, z, t) = -\frac{2\pi}{L_x^2 L_y L_z} \sum_{n=1}^{\infty} n F_{nC} c_n(x) c_n(y) c_n(z) e_{nC}(t) \int_0^t e_{nC}(-\tau) \int_0^{L_x} s_n(u) \int_0^{L_y} c_n(v) \int_0^{L_z} g_L(u, v, w, T) \times$$

$$\times c_n(w) \frac{\partial C_{i-10}(u, v, w, \tau)}{\partial u} dw dv du d\tau - \frac{2\pi}{L_x L_y L_z^2} \sum_{n=1}^{\infty} n F_{nC} c_n(x) c_n(y) c_n(z) e_{nC}(t) \int_0^t e_{nC}(-\tau) \times$$

$$\times \int_0^{L_x} c_n(u) \int_0^{L_y} s_n(v) \int_0^{L_z} c_n(v) g_L(u, v, w, T) \frac{\partial C_{i-10}(u, v, w, \tau)}{\partial v} dw dv du d\tau - \frac{2\pi}{L_x L_y L_z^2} \sum_{n=1}^{\infty} n F_{nC} e_{nC}(t) \times$$

$$\times c_n(x) c_n(y) c_n(z) \int_0^t e_{nC}(-\tau) \int_0^{L_x} c_n(u) \int_0^{L_y} c_n(v) \int_0^{L_z} s_n(v) g_L(u, v, w, T) \frac{\partial C_{i-10}(u, v, w, \tau)}{\partial w} dw dv du d\tau, i \geq 1;$$

$$C_{01}(x, y, z, t) = -\frac{2\pi}{L_x^2 L_y L_z} \sum_{n=1}^{\infty} n F_{nC} c_n(x) c_n(y) c_n(z) e_{nC}(t) \int_0^t e_{nC}(-\tau) \int_0^{L_x} s_n(u) \int_0^{L_y} c_n(v) \int_0^{L_z} c_n(w) \times$$

$$\times \frac{C_{00}^\gamma(u, v, w, \tau)}{P^\gamma(u, v, w, T)} \frac{\partial C_{00}(u, v, w, \tau)}{\partial u} dw dv du d\tau - \frac{2\pi}{L_x L_y L_z^2} \sum_{n=1}^{\infty} n F_{nC} c_n(x) c_n(y) c_n(z) e_{nC}(t) \times$$

$$\times \int_0^t e_{nC}(-\tau) \int_0^{L_x} c_n(u) \int_0^{L_y} s_n(v) \int_0^{L_z} c_n(w) \frac{C_{00}^\gamma(u, v, w, \tau)}{P^\gamma(u, v, w, T)} \frac{\partial C_{00}(u, v, w, \tau)}{\partial v} dw dv du d\tau - \frac{2\pi}{L_x L_y L_z^2} \sum_{n=1}^{\infty} n e_{nC}(t) \times$$

$$\times F_{nC} c_n(x) c_n(y) c_n(z) \int_0^t e_{nC}(-\tau) \int_0^{L_x} c_n(u) \int_0^{L_y} c_n(v) \int_0^{L_z} s_n(w) \frac{C_{00}^\gamma(u, v, w, \tau)}{P^\gamma(u, v, w, T)} \frac{\partial C_{00}(u, v, w, \tau)}{\partial w} dw dv du d\tau;$$

$$C_{02}(x, y, z, t) = -\frac{2\pi}{L_x^2 L_y L_z} \sum_{n=1}^{\infty} n F_{nC} c_n(x) c_n(y) c_n(z) e_{nC}(t) \int_0^t e_{nC}(-\tau) \int_0^{L_x} s_n(u) \int_0^{L_y} c_n(v) \int_0^{L_z} c_n(w) \times$$

$$\times C_{01}(u, v, w, \tau) \frac{C_{00}^{\gamma-1}(u, v, w, \tau)}{P^\gamma(u, v, w, T)} \frac{\partial C_{00}(u, v, w, \tau)}{\partial u} dw dv du d\tau - \frac{2\pi}{L_x L_y L_z^2} \sum_{n=1}^{\infty} F_{nC} c_n(x) c_n(y) \times$$

$$\begin{aligned}
& \times n c_n(z) e_{nC}(t) \int_0^t e_{nC}(-\tau) \int_0^{L_x} c_n(u) \int_0^{L_y} s_n(v) \int_0^{L_z} C_{01}(u, v, w, \tau) \frac{C_{00}^{\gamma-1}(u, v, w, \tau)}{P^\gamma(u, v, w, T)} \frac{\partial C_{00}(u, v, w, \tau)}{\partial v} \times \\
& \times c_n(w) d w d v d u d \tau - \frac{2\pi}{L_x L_y L_z^2} \sum_{n=1}^{\infty} n F_{nC} c_n(x) c_n(y) c_n(z) e_{nC}(t) \int_0^t e_{nC}(-\tau) \int_0^{L_x} c_n(u) \int_0^{L_y} c_n(v) \times \\
& \times \int_0^{L_z} s_n(w) C_{01}(u, v, w, \tau) \frac{C_{00}^{\gamma-1}(u, v, w, \tau)}{P^\gamma(u, v, w, T)} \frac{\partial C_{00}(u, v, w, \tau)}{\partial w} d w d v d u d \tau - \frac{2\pi}{L_x^2 L_y L_z} \sum_{n=1}^{\infty} n c_n(x) \times \\
& \times F_{nC} c_n(y) c_n(z) e_{nC}(t) \int_0^t e_{nC}(-\tau) \int_0^{L_x} s_n(u) \int_0^{L_y} c_n(v) \int_0^{L_z} c_n(w) C_{01}(u, v, w, \tau) \frac{\partial C_{00}(u, v, w, \tau)}{\partial u} \times \\
& \times \frac{C_{00}^{\gamma-1}(u, v, w, \tau)}{P^\gamma(u, v, w, T)} d w d v d u d \tau - \frac{2\pi}{L_x L_y L_z^2} \sum_{n=1}^{\infty} n F_{nC} c_n(x) c_n(y) c_n(z) e_{nC}(t) \int_0^t e_{nC}(-\tau) \int_0^{L_x} c_n(u) \times \\
& \times \int_0^{L_y} s_n(v) \int_0^{L_z} c_n(w) C_{01}(u, v, w, \tau) \frac{C_{00}^{\gamma-1}(u, v, w, \tau)}{P^\gamma(u, v, w, T)} \frac{\partial C_{00}(u, v, w, \tau)}{\partial v} d w d v d u d \tau - \frac{2\pi}{L_x L_y L_z^2} \sum_{n=1}^{\infty} n \times \\
& \times F_{nC} c_n(x) c_n(y) c_n(z) e_{nC}(t) \int_0^t e_{nC}(-\tau) \int_0^{L_x} c_n(u) \int_0^{L_y} c_n(v) \int_0^{L_z} s_n(w) C_{01}(u, v, w, \tau) \frac{C_{00}^{\gamma-1}(u, v, w, \tau)}{P^\gamma(u, v, w, T)} \times \\
& \times \frac{\partial C_{00}(u, v, w, \tau)}{\partial w} d w d v d u d \tau - \frac{2\pi}{L_x^2 L_y L_z} \sum_{n=1}^{\infty} F_{nC} c_n(x) c_n(y) c_n(z) e_{nC}(t) \int_0^t e_{nC}(-\tau) \int_0^{L_x} s_n(u) \times \\
& \times n \int_0^{L_y} c_n(v) \int_0^{L_z} c_n(w) \frac{C_{00}^\gamma(u, v, w, \tau)}{P^\gamma(u, v, w, T)} \frac{\partial C_{01}(u, v, w, \tau)}{\partial u} d w d v d u d \tau - \frac{2\pi}{L_x L_y^2 L_z} \sum_{n=1}^{\infty} c_n(x) e_{nC}(t) \times \\
& \times F_{nC} c_n(y) \int_0^t e_{nC}(-\tau) \int_0^{L_x} c_n(u) \int_0^{L_y} s_n(v) \int_0^{L_z} c_n(w) \frac{C_{00}^\gamma(u, v, w, \tau)}{P^\gamma(u, v, w, T)} \frac{\partial C_{01}(u, v, w, \tau)}{\partial v} d w d v d u d \tau \times \\
& \times n c_n(z) - \frac{2\pi}{L_x L_y L_z^2} \sum_{n=1}^{\infty} n F_{nC} c_n(x) c_n(y) c_n(z) e_{nC}(t) \int_0^t e_{nC}(-\tau) \int_0^{L_x} c_n(u) \int_0^{L_y} c_n(v) \int_0^{L_z} s_n(w) \times \\
& \times \frac{C_{00}^\gamma(u, v, w, \tau)}{P^\gamma(u, v, w, T)} \frac{\partial C_{01}(u, v, w, \tau)}{\partial w} d w d v d u d \tau; \\
C_{11}(x, y, z, t) = & -\frac{2\pi}{L_x^2 L_y L_z} \sum_{n=1}^{\infty} n F_{nC} c_n(x) c_n(y) c_n(z) e_{nC}(t) \int_0^t e_{nC}(-\tau) \int_0^{L_x} s_n(u) \int_0^{L_y} c_n(v) \int_0^{L_z} c_n(w) \times \\
& \times g_L(u, v, w, T) \frac{\partial C_{01}(u, v, w, \tau)}{\partial u} d w d v d u d \tau - \frac{2\pi}{L_x L_y^2 L_z} \sum_{n=1}^{\infty} n F_{nC} c_n(x) c_n(y) c_n(z) e_{nC}(t) \times \\
& \times \int_0^t e_{nC}(-\tau) \int_0^{L_x} c_n(u) \int_0^{L_y} s_n(v) \int_0^{L_z} c_n(w) g_L(u, v, w, T) \frac{\partial C_{01}(u, v, w, \tau)}{\partial v} d w d v d u d \tau - \frac{2\pi}{L_x L_y L_z^2} \times
\end{aligned}$$

$$\begin{aligned}
& \times \sum_{n=1}^{\infty} n e_{nC}(t) \int_0^t e_{nC}(-\tau) \int_0^{L_x} c_n(u) \int_0^{L_y} c_n(v) \int_0^{L_z} s_n(w) g_L(u, v, w, T) \frac{\partial C_{01}(u, v, w, \tau)}{\partial w} dw dv du d\tau \times \\
& \times F_{nC} c_n(x) c_n(y) c_n(z) - \frac{2\pi}{L_x L_y L_z} \sum_{n=1}^{\infty} F_{nC} c_n(x) c_n(y) c_n(z) e_{nC}(t) \int_0^t e_{nC}(-\tau) \int_0^{L_x} s_n(u) \int_0^{L_y} c_n(v) \times \\
& \times n \int_0^{L_z} c_n(w) \frac{C_{00}^{\gamma}(u, v, w, \tau)}{P^{\gamma}(u, v, w, T)} \frac{\partial C_{10}(u, v, w, \tau)}{\partial u} dw dv du d\tau - \frac{2\pi}{L_x L_y L_z} \sum_{n=1}^{\infty} n F_{nC} c_n(x) c_n(y) \times \\
& \times c_n(z) e_{nC}(t) \int_0^t e_{nC}(-\tau) \int_0^{L_x} c_n(u) \int_0^{L_y} s_n(v) \int_0^{L_z} c_n(w) \frac{C_{00}^{\gamma}(u, v, w, \tau)}{P^{\gamma}(u, v, w, T)} \frac{\partial C_{10}(u, v, w, \tau)}{\partial v} dw dv du d\tau - \\
& - \frac{2\pi}{L_x L_y L_z} \sum_{n=1}^{\infty} n F_{nC} c_n(x) c_n(y) c_n(z) e_{nC}(t) \int_0^t e_{nC}(-\tau) \int_0^{L_x} c_n(u) \int_0^{L_y} c_n(v) \int_0^{L_z} s_n(w) \frac{C_{00}^{\gamma}(u, v, w, \tau)}{P^{\gamma}(u, v, w, T)} \times \\
& \times \frac{\partial C_{10}(u, v, w, \tau)}{\partial w} dw dv du d\tau - \frac{2\pi}{L_x L_y L_z} \sum_{n=1}^{\infty} n F_{nC} c_n(x) c_n(y) c_n(z) e_{nC}(t) \int_0^t e_{nC}(-\tau) \int_0^{L_x} s_n(u) \times \\
& \times \int_0^{L_y} c_n(v) \int_0^{L_z} c_n(w) C_{10}(u, v, w, \tau) \frac{C_{00}^{\gamma-1}(u, v, w, \tau)}{P^{\gamma}(u, v, w, T)} \frac{\partial C_{00}(u, v, w, \tau)}{\partial u} dw dv du d\tau - \frac{2\pi}{L_x L_y L_z} \sum_{n=1}^{\infty} n \times \\
& \times F_{nC} c_n(x) c_n(y) c_n(z) e_{nC}(t) \int_0^t e_{nC}(-\tau) \int_0^{L_x} c_n(u) \int_0^{L_y} s_n(v) \int_0^{L_z} c_n(w) \frac{C_{00}^{\gamma-1}(u, v, w, \tau)}{P^{\gamma}(u, v, w, T)} \frac{\partial C_{00}(u, v, w, \tau)}{\partial v} \times \\
& \times C_{10}(u, v, w, \tau) dw dv du d\tau - \frac{2\pi}{L_x L_y L_z} \sum_{n=1}^{\infty} n F_{nC} c_n(x) c_n(y) c_n(z) e_{nC}(t) \int_0^t e_{nC}(-\tau) \int_0^{L_x} c_n(u) \times \\
& \times \int_0^{L_y} c_n(v) \int_0^{L_z} s_n(w) C_{10}(u, v, w, \tau) \frac{C_{00}^{\gamma-1}(u, v, w, \tau)}{P^{\gamma}(u, v, w, T)} \frac{\partial C_{00}(u, v, w, \tau)}{\partial w} dw dv du d\tau.
\end{aligned}$$

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